NSN 5961-01-374-5523

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-374-5523 **Inclosure Material:** Glass or ceramic **Overall Length:** Between 0.160 inches and 0.205 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.080 inches and 0.107 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-41 **Mounting Method: Terminal Features Provided:** Burn in and electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 0.55 forward voltage, dc and 20.0 emitter to collector voltage, floating potential, dc with base biased in reverse direction with respect to the collector **Current Rating Per Characteristic:** 1.00 amperes all primaries preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No